



OptoSupply

Light It Up

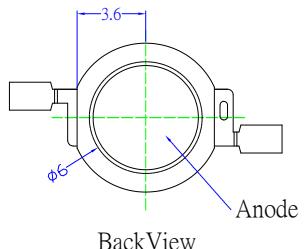
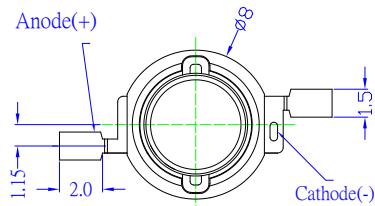
0.8W 940nm Infrared Emitter LED

OSI5XNE1C1E

■Features

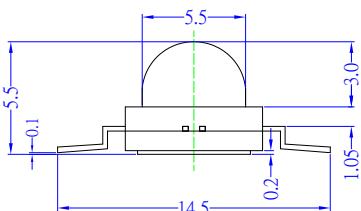
- High Radiant Power
- Super Energy Efficiency
- Long Lifetime Operation
- Superior UV Resistance

■Outline Dimension



Anode ————— Cathode

Unit:mm
Tolerance: $\pm 0.20\text{mm}$
unless otherwise noted



■Applications

- Night Vision
- Camera
- Outdoor/Indoor Applications

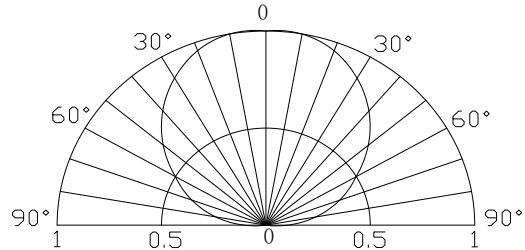
(Ta=25°C)

■Absolute Maximum Rating

Item	Symbol	Value	Unit
DC Forward Current	I _F	400	mA
Pulse Forward Current#	I _{FP}	1750	mA
Reverse Voltage	V _R	5	V
Power Dissipation	P _D	0.8	mW
Operating Temperature	T _{opr}	-30 ~ +85	°C
Storage Temperature	T _{tsg}	-40 ~ +100	°C
Lead Soldering Temperature	T _{sol}	260°C/5sec	-

#Pulse width Max.10ms Duty ratio max 1/10

■Directivity



■Electrical –Optical Characteristics

(Ta=25°C)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
DC Forward Voltage*1	V _F	I _F =350mA	-	1.65	2.0	V
DC Reverse Current	I _R	V _R =5V	-	-	10	μA
Peak Wavelength*2	λ _p	I _F =350mA	-	940	-	nm
Radiant Power*3	P _O	I _F =350mA	80	90	-	mW
Radiant Intensity*4	E _e	I _F =350mA	140	150	-	mW/Sr
50% Power Angle	2θ _{1/2}	I _F =350mA	-	120	-	deg

*1 Tolerance of measurements of forward voltage is $\pm 0.1\text{V}$

*2 Tolerance of measurements of peak wavelength is $\pm 1\text{nm}$

*3 Tolerance of measurements of Radiant Power is $\pm 15\%$

*4 Tolerance of measurements of radiant intensity is $\pm 15\%$

Note: Don't drive at rated current more than 5s without heat sink for Xeon 0.6 emitter series.

LED & Application Technologies

